

COMLINEAR® CLC2058

Dual 4V to 36V Amplifier

FEATURES

- Unity gain stable
- 100dB voltage gain
- 0.5MΩ input resistance
- 100dB power supply rejection ratio
- 4V to 36V single supply voltage range
- ±2V to ±18V dual supply voltage range
- Gain and phase match between amps
- CLC2058: improved replacement for NJM4558 and MC1458
- CLC2058: Pb-free SOIC-8

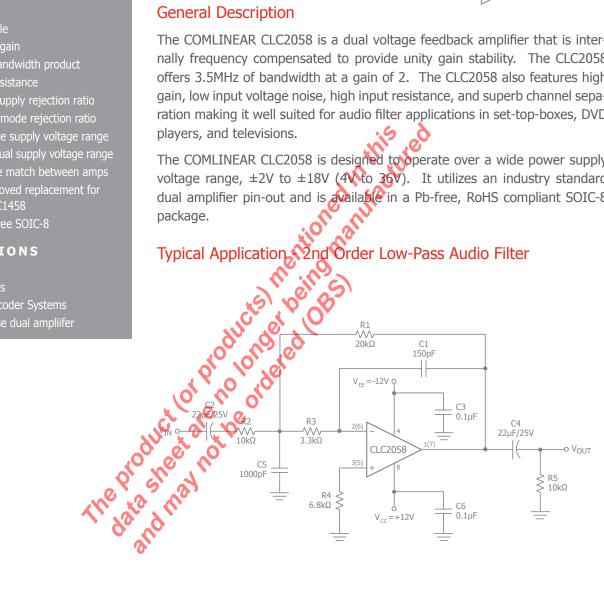
APPLICATIONS

- Audio AC-3 Decoder Systems

General Description

The COMLINEAR CLC2058 is a dual voltage feedback amplifier that is internally frequency compensated to provide unity gain stability. The CLC2058 offers 3.5MHz of bandwidth at a gain of 2. The CLC2058 also features high gain, low input voltage noise, high input resistance, and superb channel separation making it well suited for audio filter applications in set-top-boxes, DVD

The COMLINEAR CLC2058 is designed to operate over a wide power supply voltage range, $\pm 2V$ to $\pm 18V$ (4V to 36V). It utilizes an industry standard dual amplifier pin-out and is available in a Pb-free, RoHS compliant SOIC-8

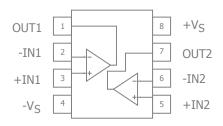


Ordering Information

Part Number	Package	Pb-Free	RoHS Compliant	Operating Temperature Range	Packaging Method
CLC2058ISO8X	SOIC-8	Yes	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1.

CLC2058 Pin Configuration



CLC2058 Pin Description

Pin No.	Pin Name	Description
1	OUT1	Output, channel 1
2	-IN1	Negative input, channel 1
3	+IN1	Positive input, channel 1
4	-V _S	Negative supply
5	+IN2	Positive input, channel 2
6	-IN2	Negative input, channel 2
7	OUT2	Output, channel 2
8	+V _S	Positive supply

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Absolute Maximum Ratings

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

Parameter	Min	Max	Unit
Supply Voltage	0	40 (±20)	V
Differential Input Voltage		60 (±30)	V
Input Voltage		30 (±15)	V
Power Dissipation (T _A = 25°C) - SOIC-8		500	mW

Reliability Information

Parameter	Min	Тур	W X	Unit
Junction Temperature		41,	150	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)		0 60	260	°C
Package Thermal Resistance		70 VII.		
SOIC-8		400		°C/W

Notes:

Package thermal resistance (θ_{JA}), JDEC standard, multi-layer test boards, still air.

Recommended Operating Conditions

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Parameter		Min	Тур	Max	Unit
Operating Temperature Range		-40		+85	°C
Supply Voltage Range	40	4 (±2)		36 (±18)	V
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Electrical Characteristics

 $T_A=25^{\circ}C\text{, }+V_S=+15V\text{, }-V_S=-15V\text{, }R_f=R_g=2k\Omega\text{, }R_L=2k\Omega\text{ to }V_S/2\text{, }G=2\text{; unless otherwise noted.}$

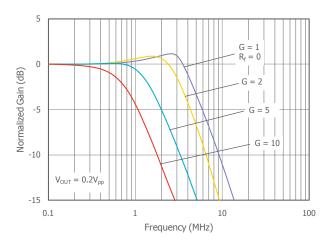
Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency D	omain Response			,		,
		$G = +1$, $V_{OUT} = 0.2V_{pp}$, $V_{S} = 5V$, $R_{f} = 0$		4.62		MHz
UGBW _{SS}	Unity Gain Bandwidth	$G = +1$, $V_{OUT} = 0.2V_{pp}$, $V_S = 30V$, $R_f = 0$		4.86		MHz
	0.15.5	$G = +2$, $V_{OUT} = 0.2V_{pp}$, $V_{S} = 5V$		3.49		MHz
BW _{SS}	-3dB Bandwidth	$G = +1$, $V_{OUT} = 0.2V_{pp}$, $V_S = 30V$		3.55		MHz
DIA.		$G = +2$, $V_{OUT} = 1V_{pp}$, $V_{S} = 5V$		1.25		MHz
BW _{LS}	Large Signal Bandwidth	$G = +2$, $V_{OUT} = 2V_{pp}$, $V_{S} = 30V$		0.74		MHz
GBWP	Gain-Bandwidth Product			5.5		MHz
Time Domaii	n Response					
	Rise and Fall Time	$V_{OUT} = 0.2V \text{ step; } (10\% \text{ to } 90\%), V_S = 5V$		100		ns
t _R , t _F	Rise and Fall Time	$V_{OUT} = 0.2V \text{ step; } (10\% \text{ to } 90\%), V_S = 30V$	0	98		ns
OS	Overshoot	V _{OUT} = 0.2V step		12		%
CD	Classification	2V step, V _S = 5V		2.6		V/µs
SR	Slew Rate	4V step, V _S = 30V		2.8		V/µs
Distortion/N	oise Response	76, 711,				
THD+N	Total Harmonic Distortion plus Noise	$V_{OUT} = 1V_{RMS}$, $f = 1kHz$, $\Omega = 2$, $\Omega = 10k\Omega$, $V_{S} = 30V$		0.002		%
		> 1kHz, V _S = 5V		10		nV/√Hz
e _n	Input Voltage Noise	> 1kHz, V _S = 30		10		nV/√Hz
X _{TALK}	Crosstalk	Channel-to-channel 500kHz		65		dB
DC Performa	ince	.0,7,7,0				
V _{IO}	Input Offset Voltage (1)	V _S = 3 0 to 300		1	5	mV
I _b	Input Bias Current (1)	V _{CM} 0V		70	400	nA
I _{OS}	Input Offset Current (1)	$Q_{M} = 0$		10	100	nA
PSRR	Power Supply Rejection Ratio (1)	$DC, R_S \leq 10 k\Omega$	80	100		dB
A _{OL}	Open-Loop Gain (1)	$R_D = \ge 2k\Omega$, $V_{OUT} = 1V$ to 11V	85	100		dB
I_{S}	Supply Current (1)	Total, R = ∞		2.5	4.5	mA
Input Charac	cteristics					
CMIR	Common Mode Input Range (1,3)	+V _S = 30V	±12			V
CMRR	Common Mode Rejection Ratio	\downarrow DC, R _S \leq 10k Ω	70	95		dB
R _{IN}	Input Resistance	•		0.5		MΩ
Output Char	Common Mode Input Range (1,3) Common Mode Rejection Ration Input Resistance acteristics Output Resistance Output Voltage Swing (1)					
R _{OUT}	Output Resistance			45		Ω
	Outside (Charles)	$R_L = 2k\Omega$	±10	±13		V
V _{OUT}	Output Voltage Swing (1)	$R_L = 10k\Omega$	±12	±14		V
I _{SOURCE}	Output Current, Sourcing	V _{IN+} = 1V, V _{IN-} = 0V, V _{OUT} = 2V		35		mA
I _{SINK}	Output Current, Sinking	V _{IN+} = 0V, V _{IN-} = 1V, V _{OUT} = 2V		60		mA

Notes:

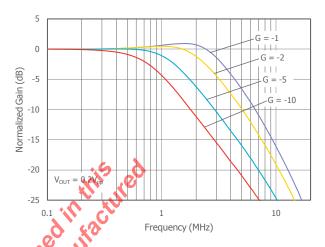
1. 100% tested at 25°C at $V_S = \pm 15V$.

 $T_A = 25$ °C, $+V_S = +15$ V, $-V_S = -15$ V, $R_f = R_q = 2k\Omega$, $R_L = 2k\Omega$ to $V_S/2$, G = 2; unless otherwise noted.

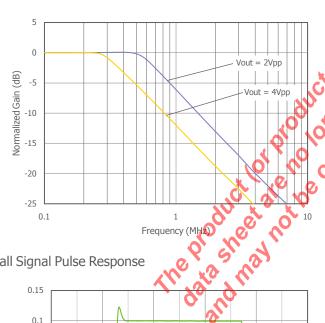
Non-Inverting Frequency Response



Inverting Frequency Response

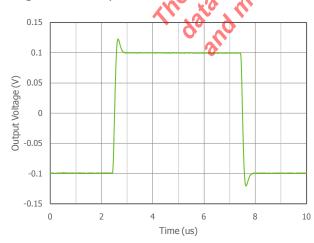


Large Signal Frequency Response

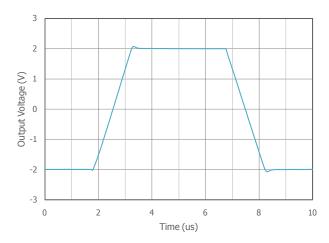




Small Signal Pulse Response

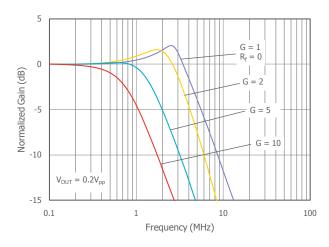


Large Signal Pulse Response

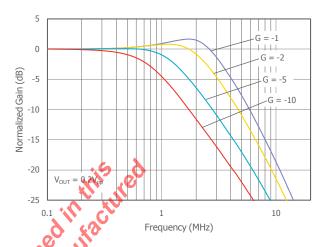


 $T_A = 25$ °C, $+V_S = +5V$, $-V_S = GND$, $R_f = R_q = 2k\Omega$, $R_L = 2k\Omega$ to $V_S/2$, G = 2; unless otherwise noted.

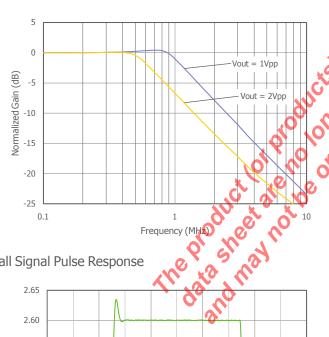
Non-Inverting Frequency Response

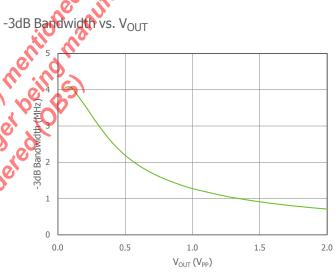


Inverting Frequency Response

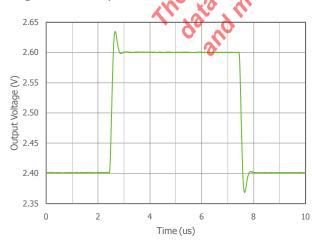


Large Signal Frequency Response

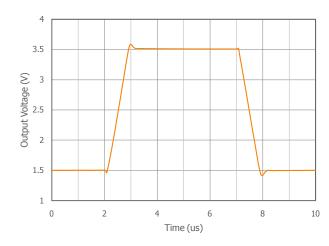




Small Signal Pulse Response

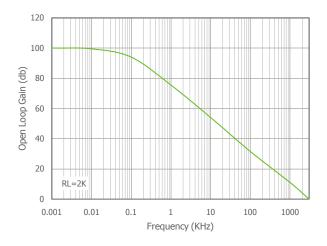


Large Signal Pulse Response

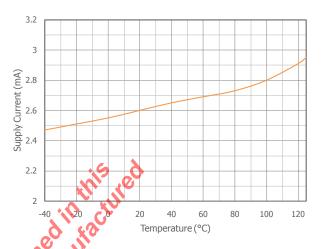


 $T_A = 25$ °C, $+V_S = +15$ V, $-V_S = -15$ V, $R_f = R_q = 2k\Omega$, $R_L = 2k\Omega$ to $V_S/2$, G = 2; unless otherwise noted.

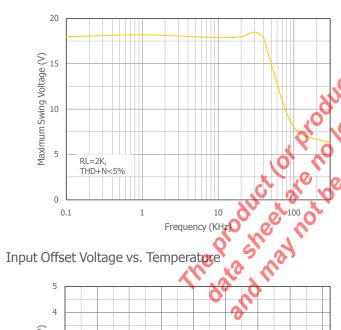
Open Loop Voltage Gain vs. Frequency



Supply Current vs. Temperature

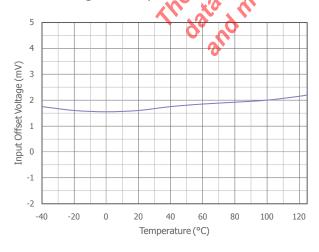


Maximum Output Voltage Swing vs. Frequency

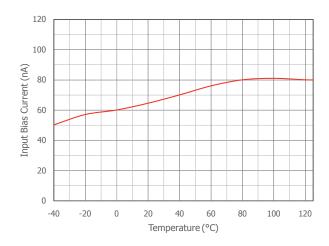


Maximum Output Voltage Swing vs. R_L



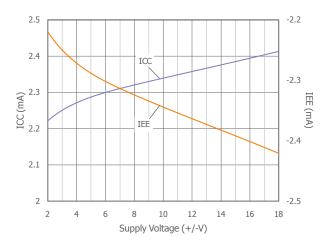


Input Bias Current vs. Temperature



 $T_A=25$ °C, $+V_S=+15$ V, $-V_S=-15$ V, $R_f=R_g=2k\Omega$, $R_L=2k\Omega$ to $V_S/2$, G=2; unless otherwise noted.

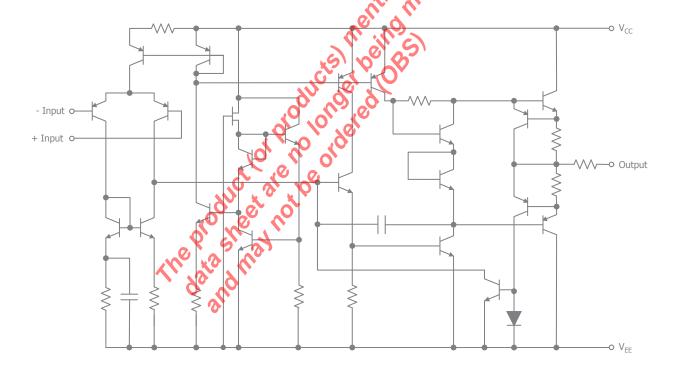
Supply Voltage vs. Supply Current



Crosstalk vs. Frequency



Functional Block Diagram



Application Information

Basic Operation

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

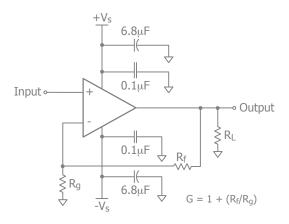


Figure 1. Typical Non-Inverting Gain Circuit

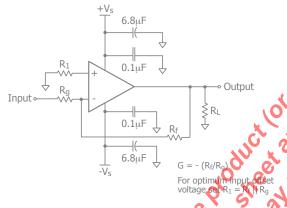


Figure 2. Typical Inverting Gain Circuit

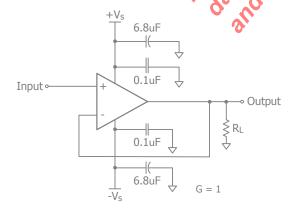


Figure 3. Unity Gain Circuit

Power Dissipation

Power dissipation should not be a factor when operating under the stated 2k ohm load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta_{JA} (Θ_{1A}) is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} \Psi (\Theta_{JA} \times P_D)$$

Where Tambient is the temperature of the working environment.

In order to determine PD, the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

Supply power is calculated by the standard power equa- $V_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$ $V_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$

$$V_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$$

$$V_{\text{supply}} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{LOAD})_{RMS^2})/Rload_{eff}$$

The effective load resistor (Rloadeff) will need to include the effect of the feedback network. For instance,

Rload_{eff} in figure 3 would be calculated as:

$$R_L \mid\mid (R_f + R_q)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, PD can be found from

$$P_D = P_{Quiescent} + P_{Dynamic} - P_{Load}$$

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{Supply}. Load power can be calculated as above with the desired signal amplitudes using:

 $(V_{LOAD})_{RMS} = V_{PEAK} / \sqrt{2}$

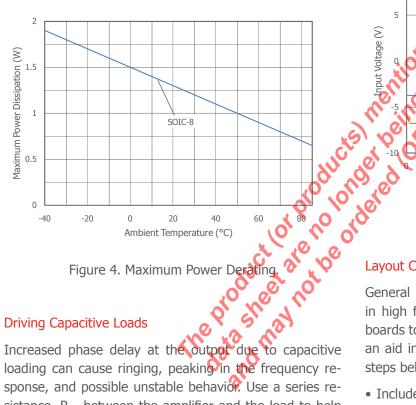
 $(I_{LOAD})_{RMS} = (V_{LOAD})_{RMS} / Rload_{eff}$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{DYNAMIC} = (V_{S+} - V_{LOAD})_{RMS} \times (I_{LOAD})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or $V_{\text{supply}}/2$.

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.



Driving Capacitive Loads

Increased phase delay at the outpot due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S, between the amplifier and the load to help improve stability and settling performance. Refer to Figure 5.

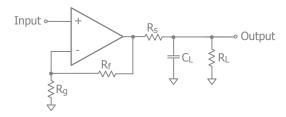


Figure 5. Addition of R_S for Driving Capacitive Loads

Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLC2058 will typically recover in less than 30ns from an overdrive condition. Figure 6 shows the CLC2058 in an overdriven condition.

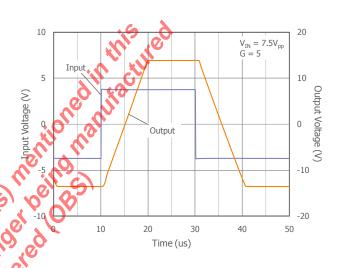


Figure 6. Overdrive Recovery

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. CADEKA has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.1µF ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board	Products
CEB006	CLC2058

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 7-9. These evaluation boards are built for dual- supply operation. Follow these steps to use the board in a single-supply application:

1. Short -Vs to ground.

2. Use C3 and C4, if the $-V_S$ pin of the amplifier is not directly connected to the ground plane.

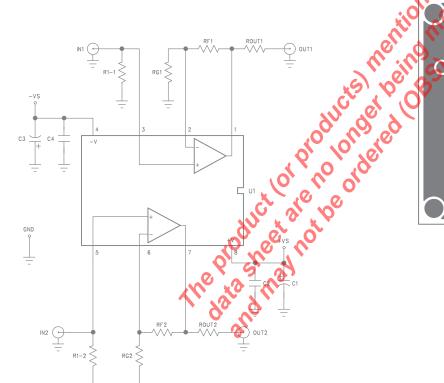


Figure 7. CEB006 Schematic

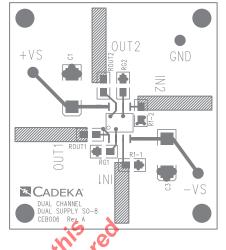


Figure 8. CEB006 Top View

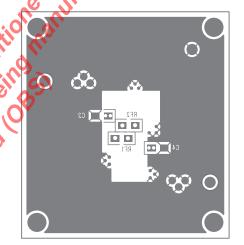
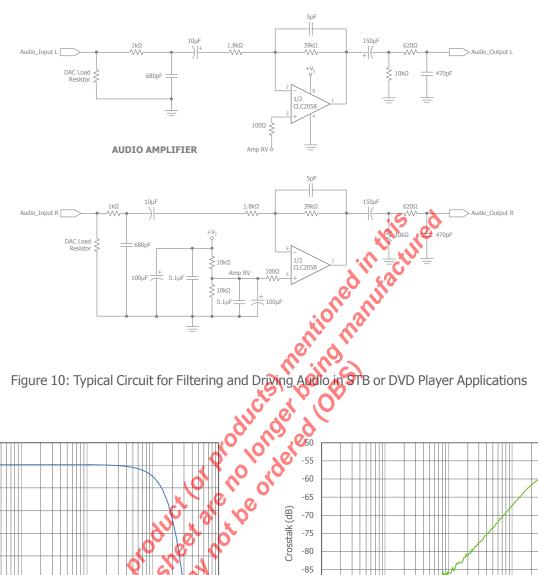


Figure 9. CEB006 Bottom View

Typical Applications



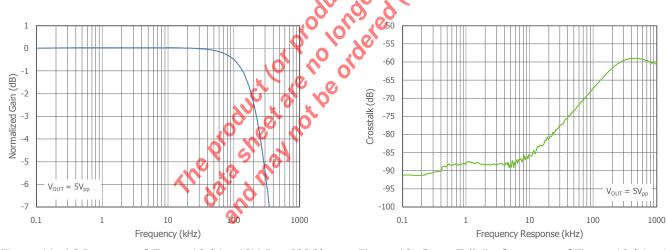
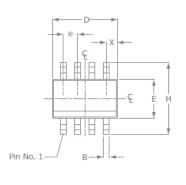


Figure 11: AC Reponse of Figure 10 ($V_S=10V$, $R_L=630\Omega$)

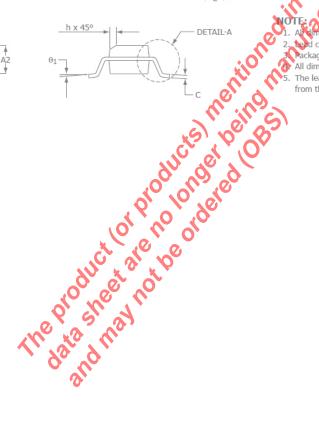
Figure 12: Cross-Talk Performance of Figure 10 (V_S=10V, $R_L=630\Omega$)

Mechanical Dimensions

SOIC-8 Package







SOIC-8					
SYMBOL	MIN	MAX			
A1	0.10	0.25			
В	0.36	0.48			
С	0.19	0.25			
D	4.80	4.98			
E	3.81	3.99			
е	1.27 BSC				
Н	5.80	6.20			
h	0.25	0.5			
L	0.41	1.27			
Α	1.37	1.73			
• 691	00	80			
Х	0.55 ref				
θ_2	7° BSC				

1. Al dimensions are in millimeters.

- 2. Lead coplanarity should be 0 to 0.1mm (0.004") max. 3 Package surface finishing: VDI 24~27
 - All dimension excluding mold flashes.
- The lead width, B to be determined at 0.1905mm from the lead tip.

For Further Assistance:

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